# imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





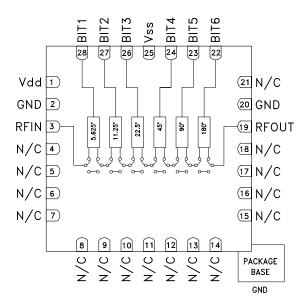


#### **Typical Applications**

The HMC649LP6(E) is ideal for:

- EW Receivers
- Weather & Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

#### **Functional Diagram**



## HMC649LP6 / 649LP6E

#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz

#### Features

Low RMS Phase Error: 3° Low Insertion Loss: 8 dB High Linearity: +44 dBm Positive Control Logic 360° Coverage, LSB = 5.625° 28 Lead QFN Leadless SMT Package: 36mm<sup>2</sup>

#### **General Description**

The HMC649LP6(E) is a 6-bit digital phase shifter which is rated from 3 - 6 GHz, providing 360 degrees of phase coverage, with a LSB of 5.625 degrees. The HMC649LP6(E) features very low RMS phase error of 3 degrees and extremely low insertion loss variation of  $\pm 0.5$  dB across all phase states. This high accuracy phase shifter is controlled with positive control logic of 0/+5V. The HMC649LP6(E) is housed in a compact 6x6 mm plastic leadless SMT package and is internally matched to 50 Ohms with no external components.

#### Electrical Specifications $T_A = +25^{\circ}$ C, Vss= -5V, Vdd= +5V, Control Voltage= 0/ +5V, 50 Ohm System

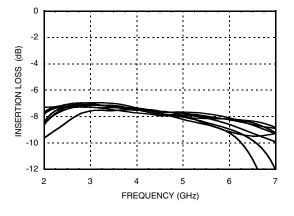
Parameter		Min.	Тур.	Max.	Units
Frequency Range		3		6	GHz
Insertion Loss*			8	10.5	dB
Input Return Loss*			13		dB
Output Return Loss*			10		dB
Phase Error*	3.0 - 5.5 GHz 5.5 - 6.0 GHz		±5 -10	+15 / -25 +15 / -32	deg deg
RMS Phase Error			3		deg
Insertion Loss Variation*			±0.5		dB
Input Power for 1 dB Compression			29		dBm
Input Third Order Intercept			44		dBm
Control Voltage Current			35	250	μA
Bias Voltage Current			5	15	mA

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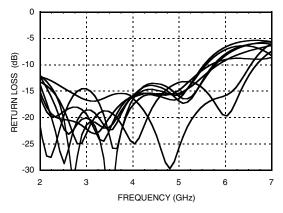




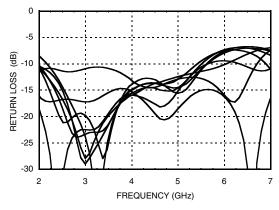
#### Insertion Loss, Major States Only



Input Return Loss, Major States Only

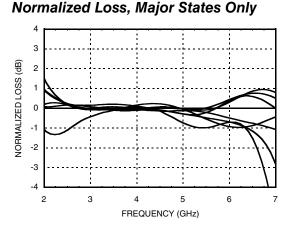


Output Return Loss, Major States Only

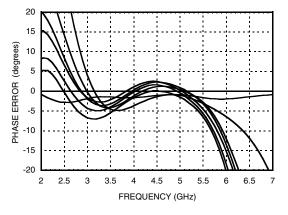


## HMC649LP6 / 649LP6E

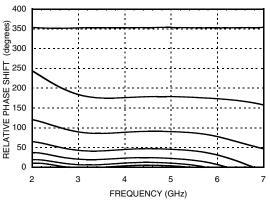
#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz



Phase Error, Major States Only



Relative Phase Shift Major States Including All Bits

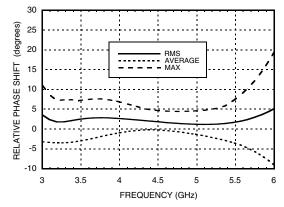


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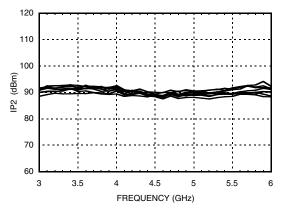




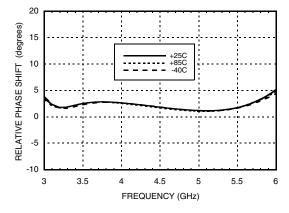
Relative Phase Shift, RMS, Average, Max, All States



Input IP2, Major States Only



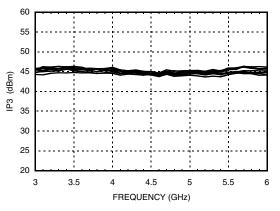
**RMS Phase Error vs. Temperature** 



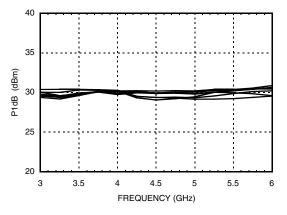
## HMC649LP6 / 649LP6E

#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz

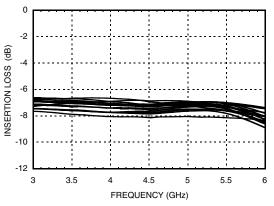




Input P1dB, Major States Only



Insertion Loss vs. Temperature, Major States Only

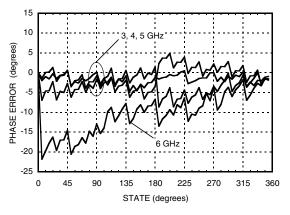


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#### Phase Error vs. State



#### Absolute Maximum Ratings

Input Power (RFIN)	32 dBm (T= +85 °C)
Bias Voltage Range (Vdd)	-0.2 to +12V
Bias Voltage Range (Vss)	+0.2 to -12V
Channel Temperature (Tc)	150 °C
Thermal Resistance (channel to ground paddle)	160 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS** 

#### **Truth Table**

Control Voltage Input						Phase Shift	
Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	(Degrees) RFIN - RFOUT	
0	0	0	0	0	0	Reference*	
1	0	0	0	0	0	5.625	
0	1	0	0	0	0	11.25	
0	0	1	0	0	0	22.5	
0	0	0	1	0	0	45.0	
0	0	0	0	1	0	90.0	
0 0 0 0 0 1 180.0						180.0	
1	1 1 1 1 1 1 354.375						
Any combination of the above states will provide a phase shift approxi- mately equal to the sum of the bits selected.							
*Reference corresponds to monotonic setting							

#### **Bias Voltage & Current**

Vdd	Idd
5.0	5.4mA
Vss	lss
-5.0	5.4mA

#### **Control Voltage**

State	Bias Condition
Low (0)	0 to 0.2 Vdc
High (1)	Vdd ±0.2 Vdc @ 35 µA Typ.

GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz

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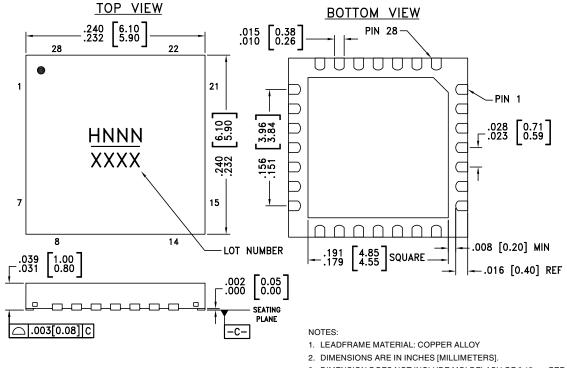




#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz



#### **Outline Drawing**



3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.

DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

6. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC649LP6	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H646 XXXX
HMC649LP6E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>H649</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



## HMC649LP6 / 649LP6E

#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz



#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	Vdd	Voltage supply.	
2, 20	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
3	RFIN	This port is DC coupled and matched to 50 Ohms.	RFIN O
4 - 18	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
19	RFOUT	This port is DC coupled and matched to 50 Ohms.	O RFOUT
22 - 24, 26 - 28	BIT6, BIT5, BIT4, BIT3, BIT2, BIT1	Control Input. See truth table and control voltage tables.	
25	Vss	Voltage supply.	

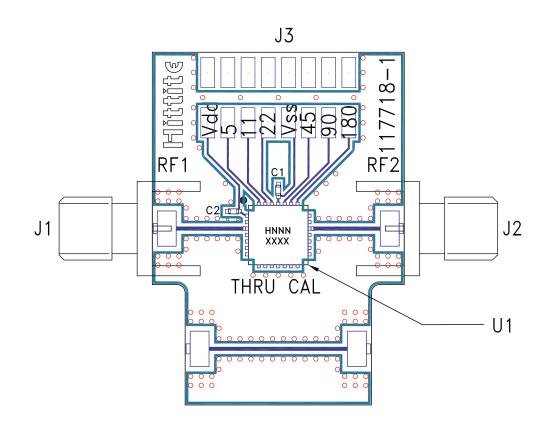


## HMC649LP6 / 649LP6E

#### GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 3 - 6 GHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 117720 [1][3]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	Header 2mm, 16 Pins
C1,C2	1000pF Capacitor, 0402 Pkg.
U1	HMC649LP6(E) 6-Bit Digital Phase Shifter
PCB [2]	117718 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

[3] Please refer to part's pin description and functional diagram for pin out assignments on evaluation board.

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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### HMC649LP6 / 649LP6E

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Notes: